# HD14051B

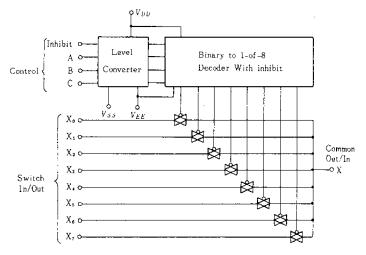
# 8-channel Analog Multiplexer/Demultiplexer

The HD14051B analog multiplexer is digitally controlled analog switch effectively implements an SP8T electronic switch and features low ON impedance and very low OFF leakage current. Control of analog signals up to the complete supply voltage range can be achieved.

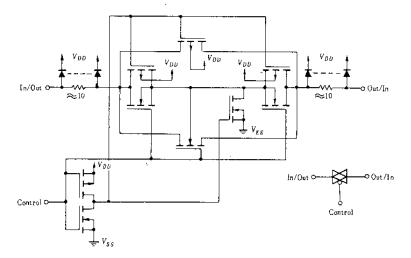
## FEATURES

- High On/Off Output Voltage Ratio = 65dB typ.
- Quiescent Current = 5nA/pkg typ. @5V
- Low Crosstalk Between Switches = 80dB typ.
- Supply Voltage Range = 3 to 18V
- Linearized Transfer Characteristics,  $\Delta R_{ON} < 60\Omega$  for Vin =  $V_{DD}$  to  $V_{EE}$  @ 15V
- Pin-for-Pin Replacement for CD4051 and MC14051B

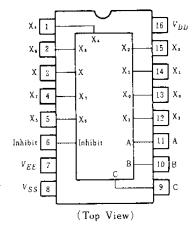
## BLOCK DIAGRAM



# SWITCH CIRCUIT SCHEMATIC



#### PIN ARRANGEMENT



## TRUTH TABLE

Contr	ol Inj	puts		O N	
Inhibit	С	В	A	Switch	
0	0	0	0	Xo	
0	0	0	1	Xı	
0	0	1	0	X2	
0	0	1	1	Х3	
0	1	0	0	X4	
0	1	0	1	X5	
0	1	1	0	X۵	
0	1	1	1	X7	
1	×	×	×	_	

x=Don't Care

**MAXIMUM RATINGS** (Voltages referenced to  $V_{ss}$ )

Characteristic	Symbol	Value	Unit
DC Supply Voltage	V <sub>DD</sub> -V <sub>EE</sub>	-0.5~+18	VDC
Controol Input Voltage	Vix	$V_{ss} = 0.5 \sim V_{DD} + 0.5$	Voc
Signal Voltage	Vsie	$V_{EE} = -0.5 \sim V_{DD} + 0.5$	V <sub>P-P</sub>
Control Input Current	I	±10	mA
Signal Current	Irig	25	mA
Operating Temperature Range	TA	-40~+85	Ĵ
Storage Temperature Range	Tete	$-65 \sim +150$	°C.
Power Dissipation -	Pp	300	mW

#### ■ ELECTRICAL CHARACTERISTICS

	C				– 40°C		25°C			85°C		Unit
Characteristic	Symbol	$V_{DD}(\mathbf{V})$	lest Co	min	тах	min	typ	max	min	max		
	VIL	5.0	$R_L = 10 \text{ k} \Omega$	$V_{o} = 0.5V$	-	1.5	_	2.25	1.5	-	1.5	
		10	SW入力=VDD	$V_{o} = 1.0 V$	_	3.0	—	4.50	3.0	_	3.0	V
		15	$V_{EE} = V_{SS}$	$V_{o} = 1.5 V$		4.0		6.75	4.0	—	4.0	
Input Voltage		5.0	$R_L = 10 \text{ k} \Omega$	$V_o = 4.0 V$	3.5	_	3.5	2.75	-	3.5	_	
	VI H	10	SW入力=Voo	<i>V</i> <sub>0</sub> =9.0V	7.0	_	7.0	5.50		7.0	_	v
		15	$V_{EE} = V_{SS}$	$V_{o} = 13.5 V$	11.0		11.0	8.25	_	11.0		
Input Current	Iin		Control, Inhib	vit	_	-	-	10	-	_		pА
Input Control, Inhibit	Cin		V <sub>in</sub> =0			-	-	5.0	_	-	_	pF
Capacitance Switch Inputs					· _	_	-	10	-			
Output Capacitance	Cour	10				_	-	60	_	_	_	pF
Feedthrough Capacitance	Cin-out	10			-	_		0.18	-	_	_	pF
Quiescent Current	IDD	5.0	Zero Signal, per Package		-	20	_	0.005	20	-	150	μA
		10			-	40	-	0.010	40	—	300	
		15				80		0.015	80	_	600	
	5.		Dynamic+I	DD.	-	-	-	0.07		_	_	
Total Supply Current	IT	10	per Gate			_		0.20	_			μA
		15	$f = 1  \mathrm{kHz}$		_		-	0.36	-	_	_	1
ON Resistance	Ron	5.0			-	880	-	250	1050	_	1200	
		10	<b>1</b> ^		_	450		120	500	_	520	ົດ
		15			-	250	-	80	280	-	300	]
△ON Resistance	1	5.0			-	_		25		_	—	
Between Any Two Channels	△ Ron	10	Two Channels		-	_	-	10	-	-	-	Ω
		15					-	5.0	-	-		
OFF Channel Leakage		1 15	Each Chann	nel	-	1000	-	±0.01	1000	-	3000	- 4
Current		15	All Channels OFF		-	1000		±0.08	1000	-	3000	- nA

\* To calculate total supply current at frequency other than  $1 \mathrm{kHz}$ .

 $@V_{DD} = 5.0V \quad I_T = (0.07 \mu \text{A/kH}z) f + I_{DD} \qquad @V_{DD} = 10V \quad I_T = (0.20 \mu \text{A/kH}z) f + I_{DD} \qquad @V_{DD} = 15V \quad I_T = (0.36 \mu \text{A/kH}z) f + I_{DD}$ 

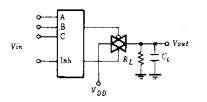
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# **SWITCHING CHARACTERISTICS** ( $C_L = 50 \text{ pF}, Ta = 25 \text{°C}$ )

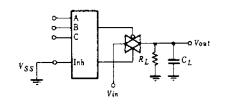
С	haracteristic	Symbol	$V_{DD}(\mathbf{V})$	Test Conditions	min	typ	max	Unit
Switch Input to Switch Output Propagation Delay Time Control Input to Output			5.0			35	90	
		<i>₹₽LH</i>	10			15	40	ns
	Switch Input to		15		_	12	30	
	<i>tphl</i>	5.0		_	35	90	ns	
		10			15	40		
		15			12	30		
	' <u>-</u>		5.0	$R_L = 10 \mathrm{k}\Omega$	_	1400	2000	ns
	Control Input to	t <sub>PLH</sub>	10		-	450	700	
			15		-	260	500	
		tphl.	5.0		-	1400	2500	
			10			450	700	ns
			15		—	260	500	]
			5.0		-	850	2125	
Output Enable Time	tzh. tzl	10			300	750	ns	
			15	$R_L = 10 \mathrm{k} \Omega$	—	250		625
			5.0	RL = 10 KeV	-	850	2125	
Output Disable Time		tHZ tLZ	10		-	300	750	ns
			15		—	250	625	
Sine Wa	we(Distortion)		10	$R_L = 1 \mathrm{k}\Omega, f = 1 \mathrm{k}\mathrm{Hz}$	-	0.04	-	%
Bandwid	th	BW	10	$R_L = 1 k\Omega, V_{in} = \frac{1}{2} (V_{DD} - V_{SS})_{p-p}, 20 \log_{10} V_{out} / V_{in} = -3 dB$	-	20	-	MHz
Feedthro	ough		10	$R_L = 1 k\Omega$ , 20logio $V_{out} / V_{iu} = -50 dB$	-	4.5	-	MHz
Channel	Separation		10	$R_L = 1k\Omega, V_{in} = \frac{1}{2}(V_{DD} - V_{SS})_{F-F}, 20\log_{10}V_{out(B)}/V_{in(A)} = -50dB$	-	3.0	—	MHz
Feedthro	ough Control		10	$R_1 = 1$ k $\Omega$ , $R_L = 10$ k $\Omega$ , Control. Inhibit $t_r = tf = 20$ ns		30	-	m۷
Maximum	Control Frequency		10	$R_L = 1 k\Omega,  V_{out} = \frac{1}{2} V_{iu}$	_	10	-	MHz

#### DC CHARACTERISTIC TEST CIRCUIT

1. Input Voltage

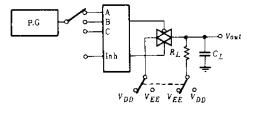


3. Bandwidth, Feedthrough



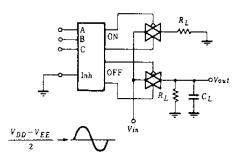
 $\frac{V_{DD} - V_{EE}}{2} + \frac{1}{2}$ 

2. Propagation Delay Time



4. Crosstalk

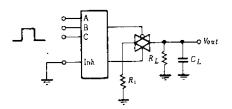
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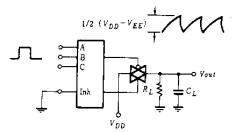


Downloaded from Elcodis.com electronic components distributor

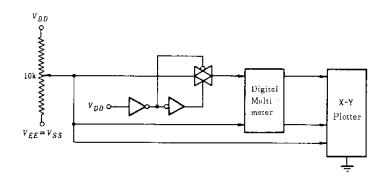
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5. Feedthrough





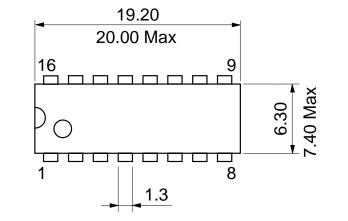




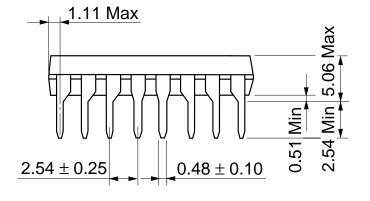
6. Maximum Control Frequency

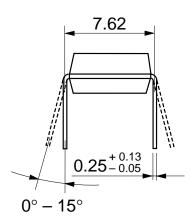


Unit: mm





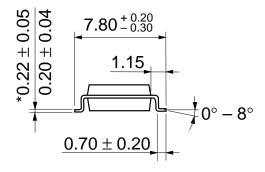




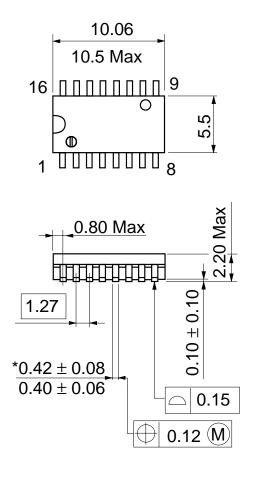
Hitachi Code	DP-16
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	1.07 g

Unit: mm



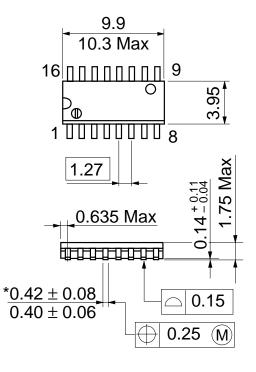


Hitachi Code	FP-16DA
JEDEC	
EIAJ	Conforms
Weight (reference value)	0.24 g



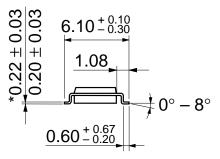
\*Dimension including the plating thickness Base material dimension

Unit: mm



\*Dimension including the plating thickness Base material dimension

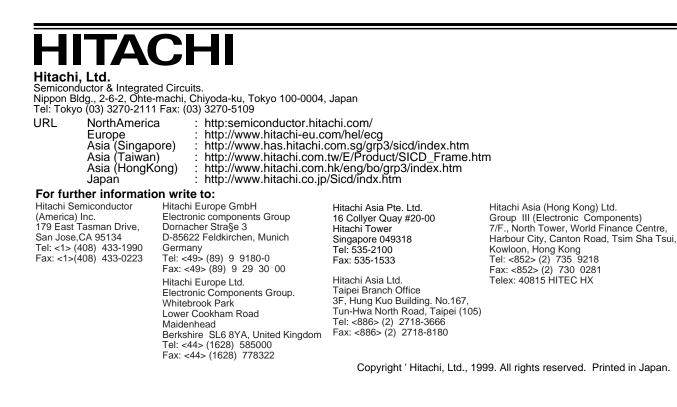




Hitachi Code	FP-16DN
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.15 g

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